## NSN 5961-00-011-6807

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View Online at https://aerobasegroup.com/nsn/5961-00-011-6807 **Inclosure Material:** Metal **Overall Length:** 0.490 inches **Overall Diameter:** 0.562 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 off-state voltage, dc **Current Rating Per Characteristic:** 15.00 milliamperes forward current, total rms preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0